National Semiconductor

LM133/LM333 3-Ampere Adjustable Negative Regulators

General Description

The LM133/LM333 are adjustable 3-terminal negative voltage regulators capable of supplying in excess of -3.0A over an output voltage range of -1.2V to -32V. These regulators are exceptionally easy to apply, requiring only 2 external resistors to set the output voltage and 1 output capacitor for frequency compensation. The circuit design has been optimized for excellent regulation and low themal transients. Further, the LM133 series features internal current limiting, thermal shutdown and safe-area compensation, making them virtually blowout-proof against overloads. The LM133/LM333 serve a wide variety of applications including local on-card regulation, programmable-output voltage regulation or precision current regulation. The LM133/ LM333 are ideal complements to the LM150/LM350 adjustable positive regulators.

Features

- Output voltage adjustable from -1.2V to -32V
- 3.0A output current guaranteed, -55°C to +150°C
- Line regulation typically 0.01%/V
- Load regulation typically 0.1%
- Excellent rejection of thermal transients
- 50 ppm/°C temperature coefficient
- Temperature-independent current limit
- Internal thermal overload protection
- 100% electrical burn-in
- Standard 3-lead transistor package
- Output is short circuit protected

Connection Diagrams

Typical Applications



TL/H/9065-1 Bottom View

Steel TO-3 Metal Can Package (K STEEL) Order Number LM133K STEEL or LM333K STEEL See NS Package Number K02A

> TO-220 Plastic Package





TL/H/9065-3

Full output current not available at high input-output voltages.

$$-V_{OUT} = -1.25V \left(1 + \frac{R^2}{120\Omega}\right) + \left(-I_{ADJ} \times R^2\right)$$

[†]C1 = 1 μ F solid tantalum or 10 μ F aluminum electrolytic required for stability.

C2 = 1 μ F solid tantalum is required only if regulator is more than 4 from power supply filter capacitor.

Output capacitors in the range of 1 µF to 1000 µF of aluminum or tantalum electrolytic are commonly used to provide improved output impedance and rejection of transients.

Absolute Maximum Ratings

If Milltary/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Power Dissipation	Internally Limited
Input-Output Voltage Differential	35V
Operating Junction Temperature Range	T _{MIN} to T _{MAX}
LM133	-55°C to +150°C
LM333	-40°C to +125°C

Storage Temperature	-65°C to +150°C
Lead Temperature (Soldering, 10 sec.)	
TO-3 Package	300°C
TO-220 Package	260°C

Preconditioning

Burn-In In Thermal Limit

100% All Devices

Electrical Characteristics LM133 (Note 1) (Note 5)

Parameter	Conditions	Typical	Tested Limit (Note 3)	Design Limit (Note 4)	Units (Max Unless Noted)
Reference Voltage	$T_J = 25^{\circ}C, I_L = 10 \text{ mA}$	-1.250	- 1.238 - 1.262		V(MIN) V(MAX)
	$ \begin{split} & T_{MIN} \leq T_{J} \leq T_{MAX}, 3V \leq V_{IN} - V_{OUT} \leq 35V, \\ & 10 \ mA \leq I_{L} \leq 3A, P \leq P_{MAX} \\ & LM133 \\ & LM133 \end{split} $	- 1.250	- 1.225 - 1.275		V(MIN) V(MAX)
Line Regulation	$\begin{split} T_J &= 25^\circ\text{C}, 3V \leq V_{\text{IN}} - V_{\text{OUT}} \leq 35\text{V}, \\ I_{\text{OUT}} &= 50 \text{ mA (Note 2)} \\ \text{LM133} \end{split}$	0.01 0.02	0.02 0.05		% /V % /V
Load Regulation	$T_J = 25^{\circ}C$, 10 mA $\leq I_{OUT} \leq$ 3A, P $\leq P_{MAX}$ (Notes 2 and 6)	0.2	0.5		%
	LM133	0.4	1.0	_	%
Thermal Regulation	T _J = 25°C, 10 ms Pulse	0.002	0.01		% /W
Temperature Stability	$T_{MIN} \le T_J \le T_{MAX}$	0.4			%
Long Term Stability	T _J = 125°C, 1000 Hours	0.15		0.8	%
Adjust Pin Current	T _J = 25°C LM133 LM133	65 70	90 100		μΑ μΑ
Adjust Pin Current Change	$\begin{array}{l} T_{J} = 25^{\circ}\text{C}, \mbox{10 mA} \leq I_{L} \leq 3\text{A} \\ T_{J} = 25^{\circ}\text{C}, \mbox{3.0V} \leq V_{IN} - V_{OUT} \leq 35\text{V} \end{array}$	2 2	5 5	6	μΑ μΑ
Minimum Load Current	$\begin{split} V_{\text{IN}} - V_{\text{OUT}} &\leq 35\text{V}, \text{T}_{\text{J}} = 25^{\circ}\text{C} \\ \text{LM133} \\ V_{\text{IN}} - V_{\text{OUT}} &\leq 10\text{V}, \text{T}_{\text{J}} = 25^{\circ}\text{C} \\ \text{LM133} \end{split}$	2.5 1.2	5.0 2.5		mA mA
Current Limit (Note 6)	$3V \le V_{IN} - V_{OUT} \le 10V, T_J = 25^{\circ}C$ LM133 $ V_{IN} - V_{OUT} = 20V, T_J = 25^{\circ}C$	3.9	3.0	-	A(MIN)
	$ V_{IN} - V_{OUT} = 20V, T_J = 25^{\circ}C$ $ V_{IN} - V_{OUT} = 30V, T_J = 25^{\circ}C$ LM133	2.4 0.4	1.25 0.3		A(MIN) A(MIN)
Output Noise (% of V _{OUT})	10 Hz to 10 kHz, T _J = 25°C	0.003	0.0	0.010	% (rms)
Ripple Rejection	$\begin{split} V_{OUT} &= 10V, f = 120 \text{ Hz}, T_J = 25^{\circ}\text{C} \\ C_{ADJ} &= 0 \ \mu\text{F} \\ C_{ADJ} &= 10 \ \mu\text{F} \end{split}$	60 77		55 70	dB dB
Thermal Resistance	TO-3 Package (K STEEL) TO-220 Package (T)	1.2 3		1.8 4	•C/W •C/W
Thermal Shutdown Temperature	LM133 LM133	163	150	190	°C(MIN) °C(MAX)

Parameter	Conditions	Typical	Tested Limit (Note 3)	Design Limit (Note 4)	Units (Max Uniess Noted)
Reference Voltage	$\begin{split} T_J &= 25^{\circ}\text{C}, \ I_L &= 10 \text{ mA} \\ T_{\text{MIN}} &\leq T_J \leq T_{\text{MAX}}, \ 3V \leq V_{\text{IN}} - V_{\text{OUT}} \leq 35V, \\ 10 \text{ mA} \leq I_L \leq 3A, \ P \leq P_{\text{MAX}} \end{split}$	-1.250 - 1.250		- 1.213 - 1.287	V(MIN) V(MAX) V(MIN) V(MAX)
Line Regulation	$T_J = 25^{\circ}C, 3V \le V_{IN} - V_{OUT} \le 35V,$ $I_{OUT} = 50 \text{ mA (Note 2)}$	0.001 0.02	0.004	0.07	% /V % /V
Load Regulation	$T_J = 25^{\circ}C$, 10 mA $\leq I_{OUT} \leq$ 3A, P $\leq P_{MAX}$ (Notes 2 and 6)	0.2 0.4	1.0	1.5	% %
Thermal Regulation	$T_{J} = 25^{\circ}C$, 10 ms Pulse	0.002	0.02		% /W
Temperature Stability	$T_{MIN} \le T_{J} \le T_{MAX}$	0.5			%
Long Term Stability	$T_{\rm J} = 125^{\circ} {\rm C}, 1000 {\rm Hours}$	0.2		0.8	%
Adjust Pin Current	$T_{\rm J} = 25^{\circ}{\rm C}$	65 70	95	100	μΑ μΑ
Adjust Pin Current Change	$T_J = 25^{\circ}C, 10 \text{ mA} \le I_L \le 3A$ $T_J = 25^{\circ}C, 3.0V \le V_{IN} \le 35V$	2.5 2.5	7 7	8 8	μΑ μΑ
Minimum Load Current	$ V_{IN} - V_{OUT} \le 35V, T_J = 25^{\circ}C$ $ V_{IN} - V_{OUT} \le 10V, T_J = 25^{\circ}C$	2.5 1.5	10 5.0	10 5.0	mA mA
Current Limit (Note 6)	$\begin{array}{l} 3V \leq V_{IN} - V_{OUT} \leq 10V, T_J = 25^\circ C \\ V_{IN} - V_{OUT} = 20V, T_J = 25^\circ C \\ V_{IN} - V_{OUT} = 30V, T_J = 25^\circ C \end{array}$	3.9 2.4 0.4	2.0 1.0 0.20	3.0 1.0 0.2	A(MIN) A(MIN) A(MIN)
Output Noise (% of V _{OUT})	10 Hz to 10 kHz, T _J = 25°C	0.003	0	0.010	% (rms)
Ripple Rejection	$V_{OUT} = 10V$, f = 120 Hz, T _J = 25°C C _{ADJ} = 0 μ F C _{ADJ} = 10 μ F	60 77		50 66	dB dB
Thermal Resistance Junction to Case	TO-3 Package (K STEEL) TO-220 Package (T)	1.2 3		1.8 4	•C/W •C/W
Thermal Shutdown Temperature		163		150 190	°C(MIN) °C(MAX)
Thermal Resistance Junction to Ambient	K Package	35		0	°C/W
(No Heatsink)	T Package	50			•C/W

Note 1: Unless otherwise specified, these specifications apply: $-55^{\circ}C \le T_J \le +150^{\circ}C$ for the LM133; and $-40^{\circ}C \le T_J + 125^{\circ}C$ for the LM333; $|V_{IN} - V_{OUT}| = 5V$; and $I_{OUT} = 0.5A$. Although power dissipation is internally limited, these specifications are applicable for power dissipations up to 30W.

Note 2: Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output voltage due to heating effects are covered under the specification for thermal regulation. Load regulation is measured on the output pin at a point 1/8" below the base of the TO-3 package. Note 3: Testing limits are guaranteed and 100% tested in production.

Note 4: Design limits are guaranteed (but not 100% production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels.

Note 5: Specifications in boldface apply over the full rated temperature range.

Note 6: The output capability of the LM333 is guaranteed at 3A in the range of $3V \le |V_{IN} - V_{OUT}| \le 10V$. At voltages above 10V, the available output current decreases, but in the range $10V \le |V_{IN} - V_{OUT}| \le 15V$, the available current is $30W - |V_{IN} - V_{OUT}|$. At voltages higher than 15V, refer to graphs for actual guaranteed output current available.





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Typical Applications (Continued)

THERMAL REGULATION

When power is dissipated in an IC, a temperature gradient occurs across the IC chip affecting the individual IC circuit components. With an IC regulator, this gradient can be especially severe since the power dissipation is large. Thermal regulation is the effect of these temperature gradients on output voltage (in percentage output change) per watt of power change in a specified time. Thermal regulation error is independent of electrical regulation or temperature coefficient, and occurs within 5 ms to 50 ms after a change in power dissipation. Thermal regulation depends on IC layout as well as electrical design. The thermal regulation of a voltage regulator is defined as the percentage change of V_{OUT}.



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FIGURE 1

per watt, within the first 10 rms after a step of power is applied. The LM133's specification is 0.01%/W, max.

In Figure 1, a typical LM133's output drifts only 2 mV (or 0.02% of $V_{OUT} = -10V$) when a 20W pulse is applied for 10 ms. This performance is thus well inside the specification limit of 0.01%/W×20W = 0.2% max. When the 20W pulse is ended, the thermal regulation again shows a 2 mV step as the LM133 chip cools off. Note that the load regulation error of about 1 mV (0.01%) is additional to the thermal regulation error. In *Figure 2*, when the 20W pulse is applied for 100 ms, the output drifts only slightly beyond the drift in the first 10 ms, and the thermal error stays well within 0.1% (10 mV).



FIGURE 2